



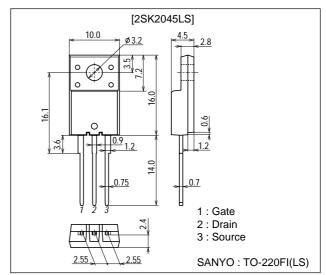
Ultrahigh-Speed Switching Applications

Features

- · Low ON-resistance.
- · Ultrahigh-speed switching.
- High-speed diode (t_{rr}=140ns).
- · Micaless package facilitating mounting.

Package Dimensions

unit : mm 2078C



Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		600	V
Gate-to-Source Voltage	VGSS		±30	V
Drain Current (DC)	ID		5.5	Α
Drain Current (Pulse)	IDP		22	Α
Allowable Power Dissipation	Do		2.0	W
	PD	Tc=25°C	35	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=10mA, VGS=0	600			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =480V, V _{GS} =0			1.0	mA
Gate-to-Source Leakage Current	IGSS	V _{GS} =±30V, V _{DS} =0			±100	nA
Cutoff Voltage	VGS(off)	V _{DS} =10V, I _D =1mA	2.0		3.0	V

(Note) Be careful in handling the 2SK2045LS because it has no protection diode between gate and source.

Continued on next page.

Marking: K2045

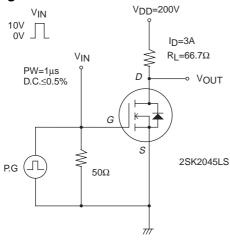
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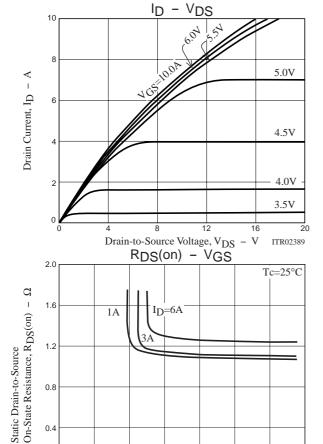
2SK2045LS

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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max] UIIII
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =3A	2.3	4.5		S
Static Drain-to-Source On-State Resistance	R _{DS} (on)	I _D =3A, V _{GS} =10V		1.1	1.5	Ω
Input Capacitance	Ciss	V _{DS} =20V, f=1MHz		1100		pF
Output Capacitance	Coss	V _{DS} =20V, f=1MHz		150		pF
Reverse Transfer Capacitance	Crss	V _{DS} =20V, f=1MHz		45		pF
Turn-ON Delay Time	td(on)	See specified Test Circuit.		18		ns
Rise Time	t _r	See specified Test Circuit.		25		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit.		240		ns
Fall Time	tf	See specified Test Circuit.		60		ns
Diode Forward Voltage	V _{SD}	I _S =5.5A, V _G S=0			1.5	V
Diode Reverse Recovery Time	t _{rr}	I _S =5.5A, di/dt=100A/μs		140		ns

Switching Time Test Circuit

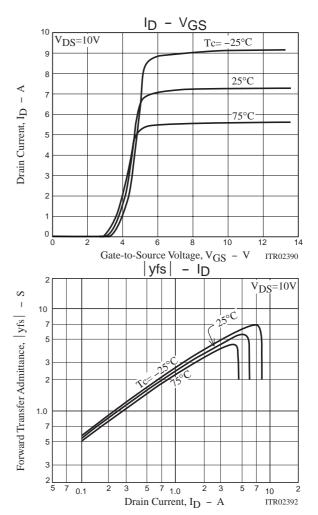


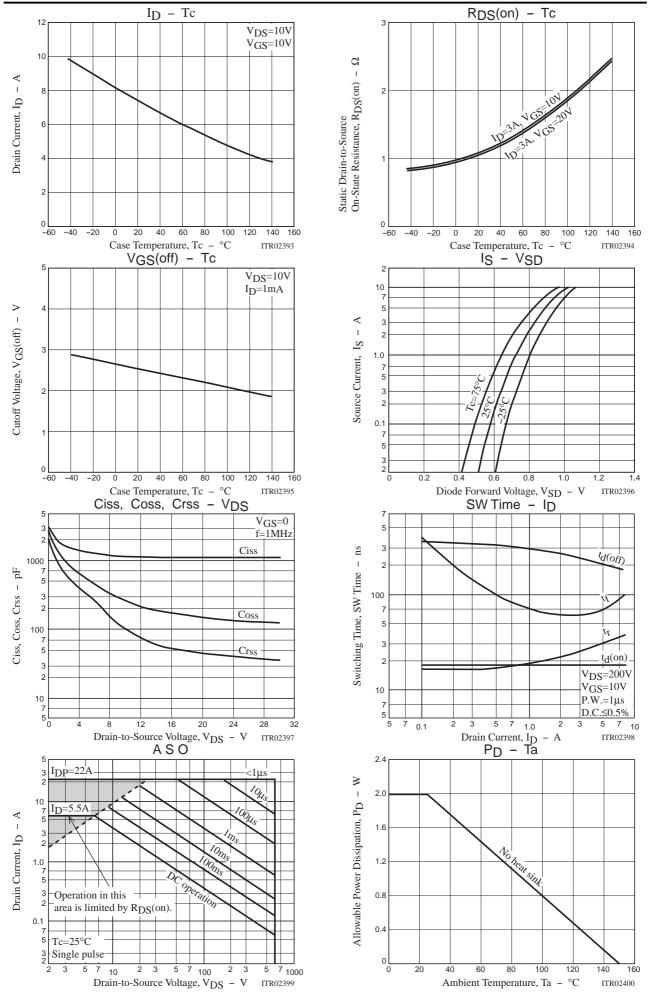


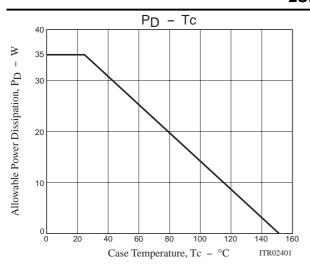
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Gate-to-Source Voltage, $V_{GS} - V$ ITR02391

0.4







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